

Model Number: ALT-G1S-L1-104-XXXX

Alto L-band Smart Amplifier

Module with low noise, high linearity, variable gain and slope control

Typical applications:

- Teleports & Earth Stations
- Satellite Operations

Hot Swap &

replaceable RF

Amplifier module

- Government & Defence applications
- Telemetry, Tracking & Command
- High Resilience applications

The extended L-band smart low noise amplifier module is designed to work in the Genus 1U chassis series, operating over 850-2150 MHz. The module has low noise, high linearity, +28 to 0 dB gain range with variable gain and slope control. The chassis has the capacity 16 amplifier modules.

Amplifier Module



Amplifier Module Compact form factor allowing multiple modules to be housed in the Genus chassis. Each module occupies 1 slot in the chassis.

Variable Gain & Slope For balancing input signals.

frequencies.



L-Band 850-2150 MHz operating frequency range



Flexible Module Configurations choose from a mixture of amplifier modules with different operating

Remote control & monitoring via RJ45

Ethernet port with SNMP & web browser interface

Field replaceable Internal 10MHz reference source and external reference inject port with auto detection (optional)

High Linearity Ensures overall RF gain signal performance is optimised

Chassis Options



Local control & monitoring via HMI high resolution touchscreen



Resilience from dual redundant hot -swap power supplies & field replaceable CPU & HMI



Compact indoor & outdoor chassis options, which can be part populated









Outdoor Unit



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		Smart Amplifier Module - RF Parameters
Model Numbers		ALT-G1S-L1-104-XXXX
Frequency Range		850-2150 MHz
RF Connectors		50Ω SMA
Gain (dB)	Max.	28±2
	Min.	0±2
Gain Flatness (dB)	850 to 2150 MHz	±0.75
	Any 36MHz	±0.2
Gain Steps (dB)		0.25±0.15
Slope Control Range (dB)		0 to 8. Pivot point at 2150 MHz
Slope Control Steps (dB)		1±0.25
Input Return Loss		18dB typ. 16 dB min
Output Return Loss		16dB typ. 14 dB min
Isolation (dB)	Тур.	60. With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB-to-dB for different gain levels.
	Min.	50 With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB-to-dB for different gain levels.
Reverse Gain (dB)		< -60 Typical
Noise Figure (dB)	Тур.	7 At max gain setting
	Min.	10 At max gain setting
1dB GCP (dBm)	Тур.	23 At max gain setting
	Min.	20 At max gain setting
OIP3 (dBm)	Тур.	32 At max gain setting
	Min.	28 At max gain setting
OIP2 (dBm)	Тур.	44
	Min.	40
In band, signal independent spurii		<-85 dBm max. Very low level spuria from CPU clock, switch mode PSU and other control electronics inside the chassis
MTBF		>150,000 hrs. MTBF of each amp module. These are hot-swap
Maximum Input Level		+20 dBm. For no damage. None operational.
Module Weight		0.35kg
Spec Version		1.1

Note 1: The specification is subject to regular reviews and will be updated from time to time as part of our continuing product development and improved spec accuracy. Note 2: Operation beyond the quoted limits stated above may cause instantaneous and permanent damage.

Note 3: All specs are for 50 Ohm connectors unless detailed otherwise.

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